



**Product data sheet** 

### 1. General description

Hyperfast power diode in a SOD113 (2-lead TO-220F) plastic package.

### 2. Features and benefits

- Isolated plastic package
- Low leakage current
- Low thermal resistance
- Low reverse recovery current
- · Reduces switching losses in associated MOSFET or IGBT

### 3. Applications

- Active PFC in air conditioner
- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- · Half-bridge/full-bridge switched-mode power supplies

### 4. Quick reference data

Symbol	Parameter	Conditions	Values				Unit
Absolute	maximum rating						
$V_{RRM}$	repetitive peak reverse voltage			6	00		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>h</sub> ≤ 51 °C; Fig. 1; Fig. 2; Fig. 3	30			A	
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>h</sub> ≤ 51 °C; square-wave pulse	60			A	
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse; <u>Fig. 4</u>	200			A	
		$t_{\rm p}$ = 8.3 ms; $T_{\rm j(init)}$ = 25 °C; sine-wave pulse			А		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 30 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	2	2.75	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	1.38	1.8	V
Dynamic	characteristics						
t <sub>rr</sub>	reverse recovery time	I <sub>F</sub> = 1 A; V <sub>R</sub> = 30 V; dI <sub>F</sub> /dt = 50 A/μs; T <sub>i</sub> = 25 °C; <u>Fig. 7</u>		-	-	35	ns

# 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	A	anode		К-Ң-А
mb	n.c.	mounting base; isolated	SOD113 (2-lead TO-220F)	001aaa020

# 6. Ordering information

Table 3. Ordering inform	nation		
Type number	Package		
	Name	Description	Version
BYC30X-600P	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

## 7. Marking

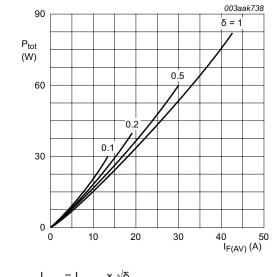
Table 4. Marking codes							
Type number	Marking codes						
BYC30X-600P	BYC30X-600P						

### 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		600	V
V <sub>RWM</sub>	crest working reverse voltage		600	V
V <sub>R</sub>	reverse voltage	DC	600	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ; square-wave pulse; T <sub>h</sub> ≤ 51 °C; Fig. 1; Fig. 2; Fig. 3	30	A
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5; t <sub>p</sub> = 25 μs; T <sub>h</sub> ≤ 51 °C; square-wave pulse	60	A
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	200	A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	220	А
T <sub>stg</sub>	storage temperature		-65 to 175	°C
Tj	junction temperature		175	°C



$$\begin{split} I_{\text{F(AV)}} &= I_{\text{F(RMS)}} \times \sqrt{\delta} \\ V_{\text{o}} &= 1.798 \text{ V; } \text{R}_{\text{s}} = 0.003 \ \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

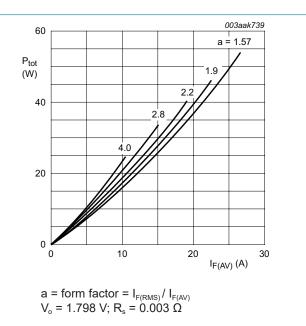
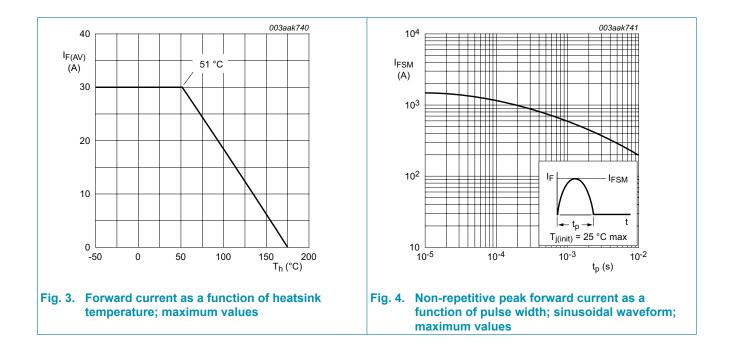


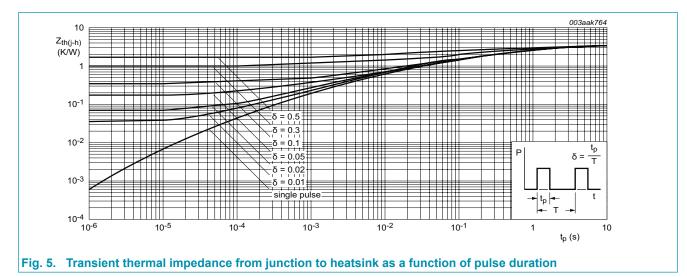
Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

BYC30X-600P Ultrafast power diode



# 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-h)}}$	thermal resistance from junction to heatsink	with heatsink compound; Fig 5	-	-	3.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



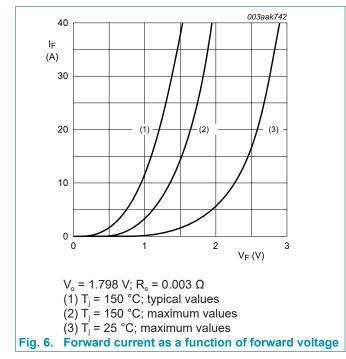
### **10. Isolation characteristics**

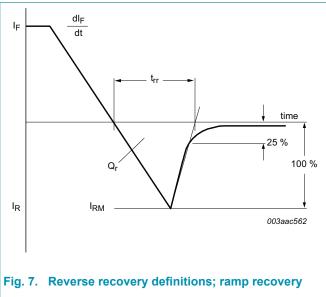
### Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>isol(RMS)</sub>	RMS isolation voltage	50 Hz $\leq$ f $\leq$ 60 Hz; RH $\leq$ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C <sub>isol</sub>	isolation capacitance	f = 1 MHz; from cathode to external heatsink	-	10	-	PF

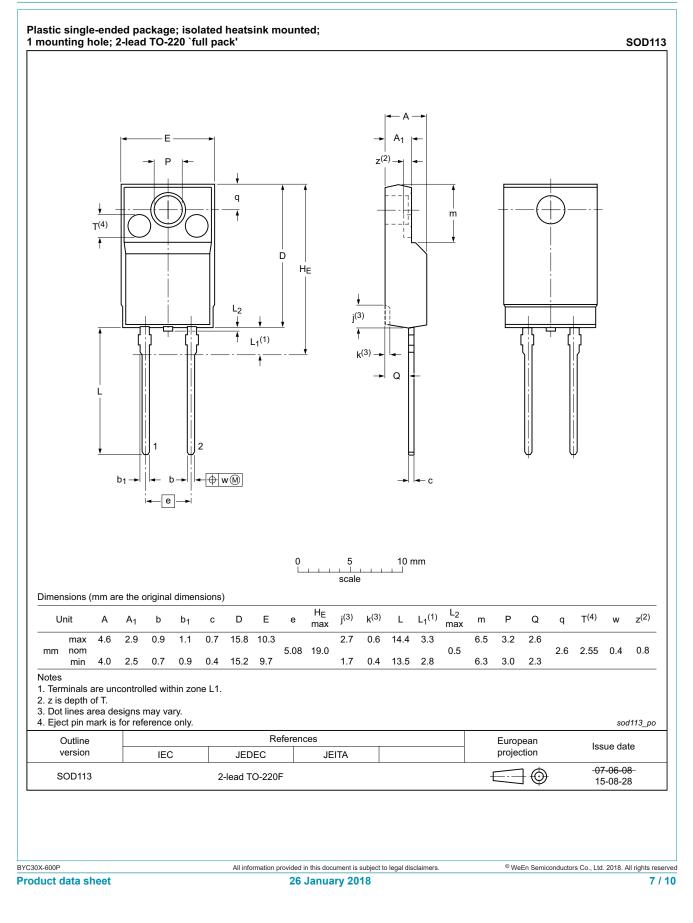
### **11. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 30 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	2	2.75	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	1.38	1.8	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 150 °C	-	-	600	μA
Dynamic	characteristics					
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	-	35	ns
		$ \begin{array}{l} I_{F} = 30 \text{ A};  V_{R} = 200 \text{ V};  \text{d} I_{F}/\text{d} t = 200 \text{ A}/\mu\text{s}; \\ T_{j} = 25 ^{\circ}\text{C};  \overline{\text{Fig. } 7} \end{array}  $	-	-	35	ns
		$ \begin{array}{l} I_{F} = 30 \text{ A};  V_{R} = 200  \text{V};  \text{d}_{\text{F}}/\text{d}\text{t} = 200  \text{A}/\mu\text{s}; \\ T_{j} = 125 ^{\circ}\text{C}; \begin{array}{c} \text{Fig. 7} \end{array}                                  $	-	70	-	ns
I <sub>RM</sub>	peak reverse recovery current	$ \begin{array}{l} {\sf I}_{\sf F} = 30 \; {\sf A}; \; {\sf V}_{\sf R} = 200 \; {\sf V}; \; {\sf dI}_{\sf F}/{\sf dt} = 200 \; {\sf A}/\mu s; \\ {\sf T}_{\sf j} = 25 \; {}^{\circ}{\sf C}; \; \overline{{\sf Fig. 7}} \end{array} $	-	3.5	-	A
		$I_{F} = 30 \text{ A}; V_{R} = 200 \text{ V}; \text{ d}_{F}/\text{d}t = 200 \text{ A}/\mu\text{s}; T_{j} = 125 \text{ °C}; Fig. 7$	-	7.6	-	A
Q <sub>r</sub>	recovered charge	$ \begin{array}{l} {\sf I}_{\sf F} = 30 \; {\sf A}; \; {\sf V}_{\sf R} = 200 \; {\sf V}; \; {\sf dI}_{\sf F}/{\sf dt} = 200 \; {\sf A}/\mu {\sf s}; \\ {\sf T}_{\sf j} = 25 \; {}^{\circ}{\sf C}; \; \overline{{\sf Fig. 7}} \end{array} $	-	50	-	nC
		I <sub>F</sub> = 30 A; V <sub>R</sub> = 200 V; dI <sub>F</sub> /dt = 200 A/μs; T <sub>i</sub> = 125 °C; <u>Fig. 7</u>	-	280	-	nC





### 12. Package outline



## 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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